



2013 IEEE International Electron Devices Meeting

*The annual meeting of the Electron Devices Society
will be held at the Washington Hilton, Washington, DC, December 9-11, 2013*

Late news papers:

Deadline for receipt of abstracts is September 11, 2013.

A very limited number of late news papers will be accepted. Late News Papers are not eligible for travel assistance or the student paper award.

Authors are asked to submit late news abstracts announcing only very recent developments. PDF files should be in the same format as a regular abstract and should be emailed to Polly Mahoney at the Conference Office. ACCEPTED LATE NEWS PAPERS AND ACCOMPANYING FIGURES WILL BE PRINTED AS RECEIVED IN THE TECHNICAL DIGEST. SUBMISSION OF A LATE NEWS PAPER FOR REVIEW WILL BE CONSIDERED BY THE REVIEW COMMITTEE AS CONSENT FROM THE AUTHOR FOR ITS PUBLICATION IF ACCEPTED. Length of the late news presentation will be ten minutes, with an additional five minutes for questions.

Meeting Highlights

- Three plenary presentations by prominent experts.
- Invited papers on all aspects of advanced devices and technologies.
- Special focus sessions covering topics in
 - BioMEMS
 - Analog devices and circuits
 - Advanced semiconductor manufacturing
 - Terahertz devices.
- Two evening panel discussions.
- Presentation of IEEE/EDS awards.
- IEDM luncheon presentation will be held on Tuesday, December 10.
- Entrepreneur's lunch at IEDM on Wednesday, December 11.
- 90 minute tutorial sessions will be offered on emerging topics, on Saturday afternoon, December 7.
- Two short courses will be held on Sunday, December 8.

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